MBR2515L

Switch-mode Power Rectifier

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 100°C Operating Junction Temperature
- 25 A Total
- Pb-Free Packages are Available*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperatures for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B

Machine Model C

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



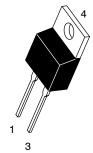
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 25 AMPERES, 15 VOLTS



MARKING DIAGRAM



TO-220AC **CASE 221B** STYLE 1



= Assembly Location = Year

WW = Work Week G = Pb-Free Package B2515L = Device Code = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
MBR2515L	TO-220	50 Units/Rail
MBR2515LG	TO-220 (Pb-Free)	50 Units/Rail

MBR2515L

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	15	V
Average Rectified Forward Current (T _C = 91°C per Device)	I _{F(AV)}	25	Α
Peak Repetitive Forward Current, per Leg (Square Wave, 20 kHz, T _C = 95°C)	I _{FRM}	25	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions, Halfwave, Single Phase, 60 Hz)	I _{FSM}	150	Α
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	1.0	Α
Storage Temperature Range	T _{stg}	-65 to +125	°C
Operating Junction Temperature	TJ	-65 to +100	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Conditions	Symbol	Max	Unit
Maximum Thermal Resistance, Junction-to-Case	Min. Pad	$R_{ heta JC}$	1.0	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	Min. Pad	$R_{\theta JA}$	70	

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Typical	Max	Unit
Instantaneous Forward Voltage (Note 1) ($i_F = 25 \text{ Amps}$, $T_j = 25^{\circ}\text{C}$) ($i_F = 25 \text{ Amps}$, $T_j = 70^{\circ}\text{C}$) ($i_F = 19 \text{ Amps}$, $T_j = 70^{\circ}\text{C}$)	VF	- - -	0.41 0.37 0.34	0.45 0.42 0.38	V
Instantaneous Reverse Current (Note 1) (Rated dc Voltage, Tj = 25°C) (Rated dc Voltage, Tj = 70°C)	i _R	- -	1.0 24	15 200	mA

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

MBR2515L

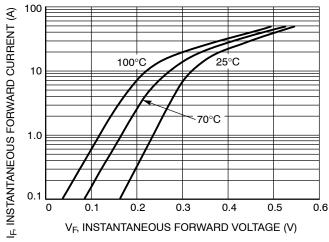


Figure 1. Typical Forward Voltage

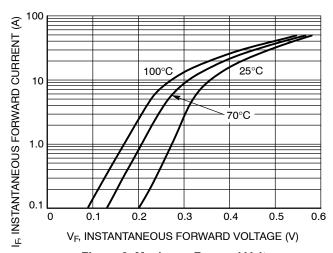


Figure 2. Maximum Forward Voltage

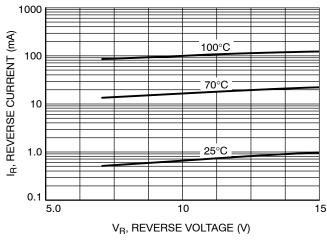


Figure 3. Typical Reverse Current

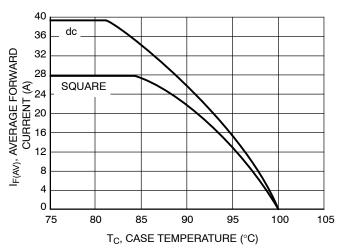


Figure 4. Current Derating, Case, Per Leg

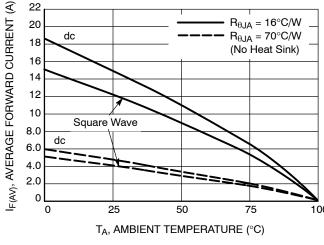


Figure 5. Current Derating, Ambient, Per Leg

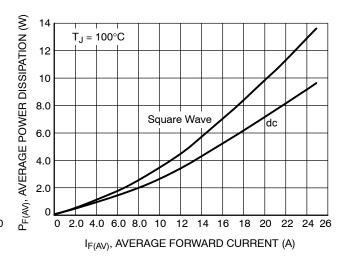


Figure 6. Forward Power Dissipation

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



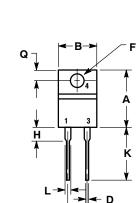


TO-220, 2-LEAD CASE 221B-04 ISSUE F

DATE 12 APR 2013

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

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	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.039	0.64	1.00
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27



STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE

PIN 1. ANODE 2. N/A 3. CATHODE 4. ANODE

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